## DN6849/SE/S

## Wide operating temperature range $\left(-40^{\circ} \mathrm{C}\right.$ to $\left.+100^{\circ} \mathrm{C}\right)$ Alternating magnetic field operation

## - Overview

In each of Hall ICs, a Hall element, an amplifier circuit, a Schmidt circuit, a stabilized power supply, and a temperature compensation circuit are integrated on a single chip by IC technique. The Hall element output is amplified by the amplifier circuit, and converted into the corresponding digital signals through the Schmidt circuit so that TTL and MOS IC are directly drivable.

## Features

- High sensitivity and low drift
- Stabilized temperature characteristics owing to additional integration of temperature compensation circuit.
- Wide operating supply voltage range
$\left(\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}\right.$ to 16 V$)$
- Alternating magnetic field operation
- TTL and MOS IC are directly drivable by the output.
- Open collector output


## Applications

- Speed sensor, position sensor, rotation sensor, keyboard switch, micro switch and the like


## Block Diagram (DN6849/SE/S)



Note) The number in ( ) shows the pin number for the DN6849S.


Note) The packages (SSIP003-P-0000A, SSIP003-P0000C and ESOP004-P-0200) of this product will be changed to lead-free type (SSIP003-P0000 H , SSIP003-P-0000J and ESOP004-P0200A). See the new package dimensions section later of this datasheet.

Absolute Maximum Ratings

| Parameter | Symbol | Rating | Unit |
| :--- | :---: | :---: | :---: |
| Supply voltage | $\mathrm{V}_{\mathrm{CC}}$ | 18 | V |
| Supply current | $\mathrm{I}_{\mathrm{CC}}$ | 8 | mA |
| Circuit current | $\mathrm{I}_{\mathrm{O}}$ | 20 | mA |
| Power dissipation | $\mathrm{P}_{\mathrm{D}}$ | 150 | mW |
| Operating ambient temperature | $\mathrm{T}_{\text {opr }}$ | -40 to +100 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature | $\mathrm{T}_{\text {stg }}$ | -55 to +125 | ${ }^{\circ} \mathrm{C}$ |

Note) This IC is not suitable for car electrical equipment.

## Recommended Operating Range

| Parameter | Symbol | Range | Unit |
| :---: | :---: | :---: | :---: |
| Supply voltage | $\mathrm{V}_{\mathrm{CC}}$ | 4.5 to 16 | V |

Electrical Characteristics at $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
| :--- | :---: | :--- | :---: | :---: | :---: | :---: |
| Operating magnetic flux density | $\mathrm{B}_{1(\mathrm{~L}-\mathrm{H})}$ | $\mathrm{V}_{\mathrm{CC}}=12 \mathrm{~V}$ | -17.5 | -6 | - | mT |
|  | $\mathrm{B}_{2(\mathrm{H}-\mathrm{L})}$ | $\mathrm{V}_{\mathrm{CC}}=12 \mathrm{~V}$ | - | 6 | 17.5 | mT |
| Hysteresis width | BW | $\mathrm{V}_{\mathrm{CC}}=12 \mathrm{~V}$ | 7 | 10 | - | mT |
| Output voltage | $\mathrm{V}_{\mathrm{OL}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $16 \mathrm{~V}, \mathrm{I}_{\mathrm{O}}=12 \mathrm{~mA}$, <br> $\mathrm{B}=17.5 \mathrm{mT}$ | - | - | 0.4 | V |
| Output current | $\mathrm{I}_{\mathrm{OH}}$ | $\mathrm{V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ to $16 \mathrm{~V}, \mathrm{~V}_{\mathrm{O}}=16 \mathrm{~V}$, <br> $\mathrm{B}=-17.5 \mathrm{mT}$ | - | - | 10 | $\mu \mathrm{~A}$ |
|  |  |  |  |  |  |  |
|  |  | $\mathrm{V}_{\mathrm{CC}}=16 \mathrm{~V}$ | - | - | 6 | mA |
|  | $\mathrm{~V}_{\mathrm{CC}}=4.5 \mathrm{~V}$ | - | - | 5.5 | mA |  |

Note) 1. The variation of operating magnetic flux density does not depend on supply voltage due to its built-in stabilized power source. ( $\mathrm{V}_{\mathrm{CC}}$ should be confined to the range of 4.5 V to 16 V .)
2. A supply current increases by approximately 1 mA when its output level varies from high to low.

## - Technical Data

- Position of Hall element (unit: mm)

A Hall element is placed on the shaded part in the figure.

| DN6849 | DN6849SE | DN6849S |
| :---: | :---: | :---: |
|  |  |  |
| Distance from package surface to sensor part |  |  |
| 0.7 | 0.42 | 0.65 |

Technical Data (continued)

- Magneto-electro conversion characteristics


Applying direction of magnetic flux

- Main characteristics

Supply current - Ambient temperature


Operating magnetic flux density - Supply voltage



Operating magnetic flux density - Ambient temperature


Low-level output voltage - Ambient temperature


## Caution on Use of Hall ICs

The Hall ICs are often used to detect movement. In such cases, the position of the Hall IC may be changed by exposition to shock or vibration over a long period of time, and it causes the detection level change. To prevent this, fix the package with adhesives or fix it on a dedicated case.

## 1. A case using an adhesive

Some kinds of adhesive generate corrosive gas (such as chloric gas) during curing. This corrosive gas corrodes the aluminum on the surface of the Hall IC, and may cause a functional defect of disconnection.

If Hall IC is to be sealed after installation, attention should be given to the adhesive or resin used for peripherals and substrate cleaner, as well as to the adhesive used for Hall IC installation. Please confirm the above matter to those manufacturers before using.

We could not select the specified adhesive, for we find it difficult to guarantee the ingredient of each adhesive.

## 2. A case bending lead wire

Bend the lead wire without stressing the package.


Bending method of lead wire


Bending position of lead wire
*: The distance can be within 3 mm , if no stress is applied to the resin mold by tightly fixing the lead wires with a metallic mold or the like.

## 3. Power supply line/Power transmission line

If a power supply line/power transmission line becomes longer, noise and/or oscillation may be found on the line. In this case, set the capacitor of $0.1 \mu \mathrm{~F}$ to $10 \mu \mathrm{~F}$ near the Hall IC to prevent it.

If a voltage of 18 V or more is thought to be applied to the power supply line (flyback voltage from coil or the ignition pulse, etc.), avoid it with external components (capacitor, resistor, Zener diode, diode, surge absorbing elements, etc.).
4. On mounting of the surface mount type package (ESOP004-P-0200)

Set pin 2 of the ESOP004-P-0200 package open, or connect it to GND. The IC will be damaged if it is connected to $\mathrm{V}_{\mathrm{CC}}$.

When mounted on the printed circuit board, the Hall IC may be highly stressed by the warp that may occur from the soldering. This may also cause a change in the operating magnetic flux density and a deterioration of its resistance to moisture.


Correct

## 5. $\mathrm{V}_{\mathrm{CC}}$ and GND

Do not reverse $\mathrm{V}_{\mathrm{CC}}$ and GND. If the $\mathrm{V}_{\mathrm{CC}}$ and GND pins are reversely connected, this IC will be destroyed. If the IC GND-pin voltage is set higher than other pin voltage, the IC configuration will become the same as a forward biased diode. Therefore, it will turn on at the diode forward voltage (approximately 0.7 V ), and a large current will flow through the IC, ending up in its destruction. (This is common to monolithic IC.)

## 6. Cautions on power-on of Hall IC

When a Hall IC is turned on, the position of the magnet or looseness may change the output of a Hall IC, and a pulse may be generated. Therefore, care should be given whenever the output state of a Hall IC is critical when the supply power is on.

## Caution on Use of Hall ICs (continued)

## 7. Fixing a Hall IC

When the Hall IC of an insertion type package installed by soldering the lead wire only is to be used under vibration, fix it firmly with a holder. Otherwise, vibration may cause metal fatigue in the lead wire of Hall IC, resulting in wire breakage.

## 8. On fixing a Hall IC to holder

When a Hall IC is mounted on the printed circuit board with a holder and the coefficient of expansion of the holder is large, the lead wire of the Hall IC will be stretched and it may give a stress to the Hall IC.

If the lead wire is stressed intensely due to the distortion of holder or board, the adhesives between the package and the lead wire may be weakened and cause a minute gap resulting in the deterioration of its resistance to moisture.

Sensitivity may also be changed by this stress.

## 9. On using flux in soldering

Choose a flux which does not include ingredients from halogen group, such as chlorine, fluorine, etc. The ingredients of halogen group may enter where the lead frame and package resin joint, causing corrosion and the disconnection of the aluminum wiring on the surface of an IC chip.
10. In case of the magnetic field of a magnet is too strong

Output may be inverted when applying a magnetic flux density of 100 mT or more. Accordingly, magnetic flux density should be used within the range of 100 mT .
11. On mounting, deburring and soldering of insertion type package

If the leads of a Hall IC in an insertion type package are inserted up to their root part through holes on the printed circuit board, abnormal stress is applied to the package and the reliability of the Hall IC is likely to deteriorate. So, when mounting each Hall IC of the insertion type, insert the leads in due degree at which the bottom face of the package is separated at least 2 mm from the top face of the PCB.

Also note that burrs of epoxy resin may be left sticking to the lead wires. (We are trying to remove such burrs as


When soldering the leads, remenber to separate the soldering position by 2 mm or more from the resin part of the package.
much as possible in the deburring process, but in some cases, they are not perfectly removable.)

## 12. On surface treatment of mini-mold package <br> Surface treatment is available in either smooth or dull finish.

13. On soldering of the surface mount type package

Surface mounting type Hall ICs are apt to change its electrical characteristics due to the stress from soldering at mounting. Therefore, avoid the mounting by flow (dipping) and a soldering iron. Please mount it by reflow soldering abiding by its recommended conditions.

- New Package Dimensions (Unit: mm)
- SSIP003-P-0000H (Lead-free package)


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- SSIP003-P-0000J (Lead-free package)

- ESOP004-P-0200A (Lead-free package)


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